

SHINDENGEN

General Purpose Rectifiers

SIL Bridges

D6SB80

800V 6A

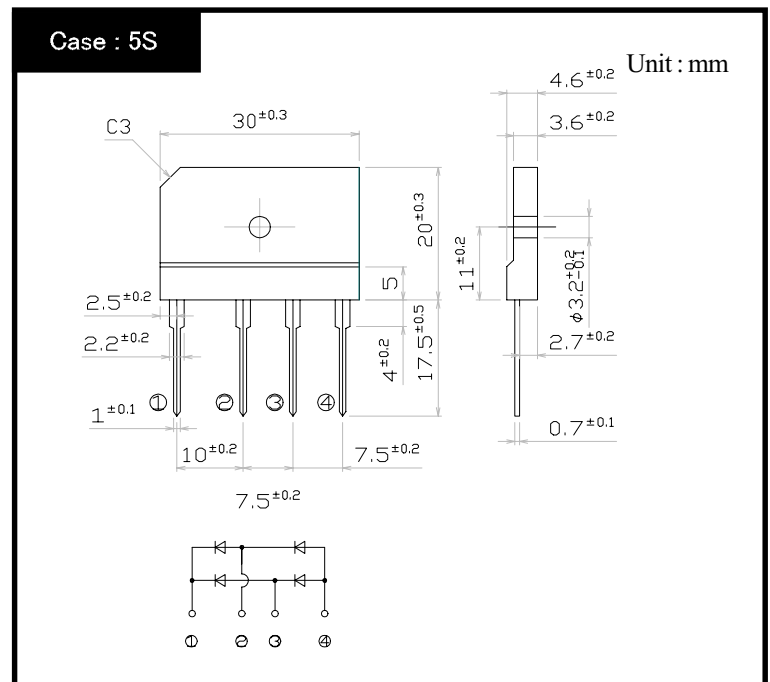
FEATURES

- Thin Single In-Line Package
- High IFSM
- Applicable to Automatic Insertion

APPLICATION

- Switching power supply
- Home Appliances, Office Equipment
- Telecommunication, Factory Automation

OUTLINE DIMENSIONS



RATINGS

●Absolute Maximum Ratings (If not specified $T_c=25^\circ\text{C}$)

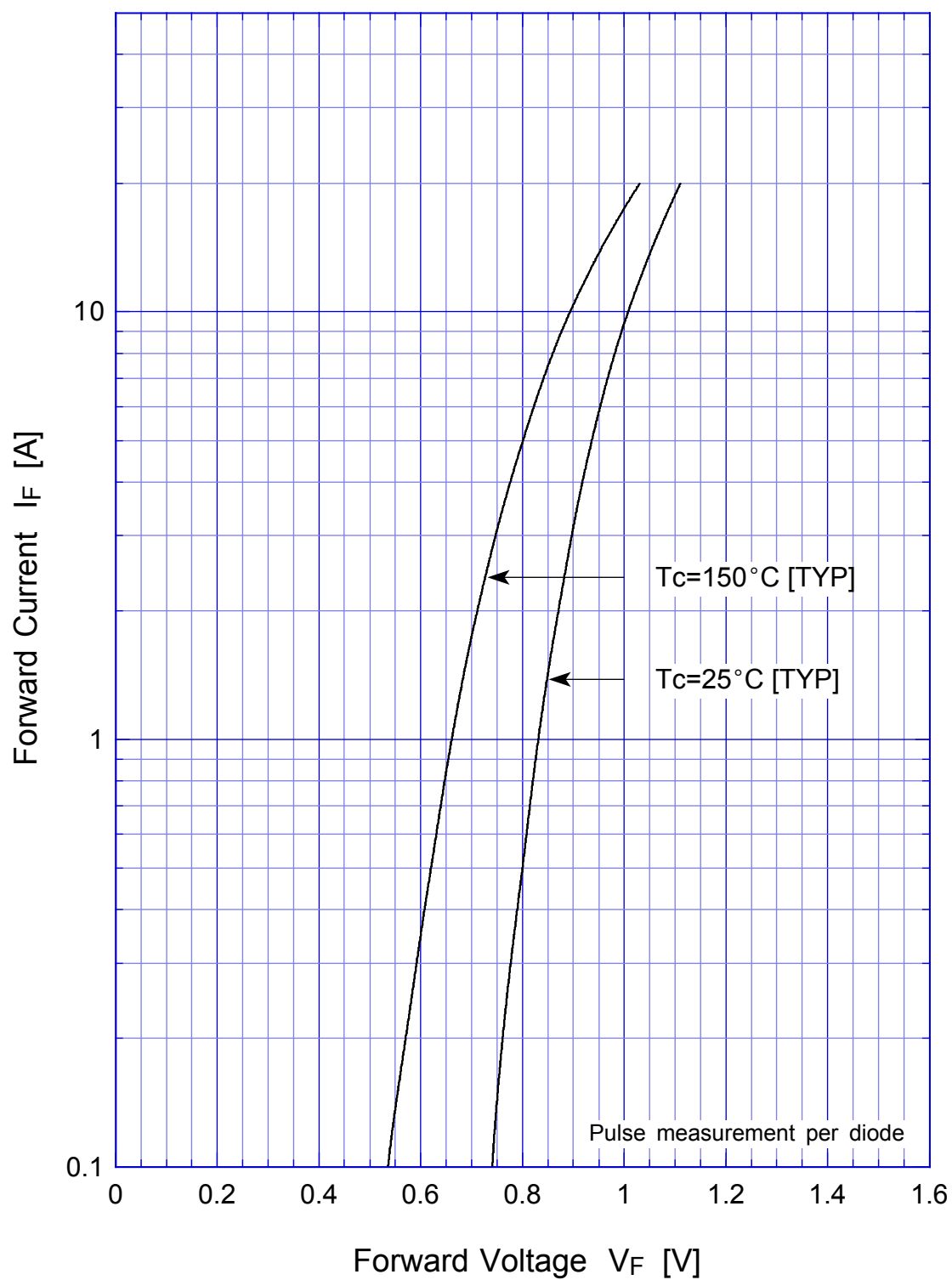
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-40~150	$^\circ\text{C}$
Operating Junction Temperature	T_j		150	$^\circ\text{C}$
Maximum Reverse Voltage	V_{RM}		800	V
Average Rectified Forward Current	I_O	50Hz sine wave, R-load With heatsink $T_c=110^\circ\text{C}$	6	A
		50Hz sine wave, R-load Without heatsink $T_a=25^\circ\text{C}$	2.8	
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, $T_j=25^\circ\text{C}$	170	A
Current Squared Time	I^2t	$2\text{ms} \leq t < 10\text{ms}$ $T_j=25^\circ\text{C}$	140	A^2s
Dielectric Strength	V_{dis}	Terminals to case, AC 1 minute	2.5	kV
Mounting Torque	TOR	(Recommended torque: $0.5\text{N}\cdot\text{m}$)	0.8	$\text{N}\cdot\text{m}$

●Electrical Characteristics (If not specified $T_c=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	$I_F=3.0\text{A}$, Pulse measurement, Rating of per diode	Max. 1.05	V
Reverse Current	I_R	$V_R=V_{RM}$, Pulse measurement, Rating of per diode	Max.10	μA
Thermal Resistance	θ_{jc}	junction to case With heatsink	Max.3.4	$^\circ\text{C}/\text{W}$
	θ_{jl}	junction to lead Without heatsink	Max.5	
	θ_{ja}	junction to ambient Without heatsink	Max.26	
	θ_{cf}	case to heatsink, Mounting torque $0.5\text{N}\cdot\text{m}$	Max.2	

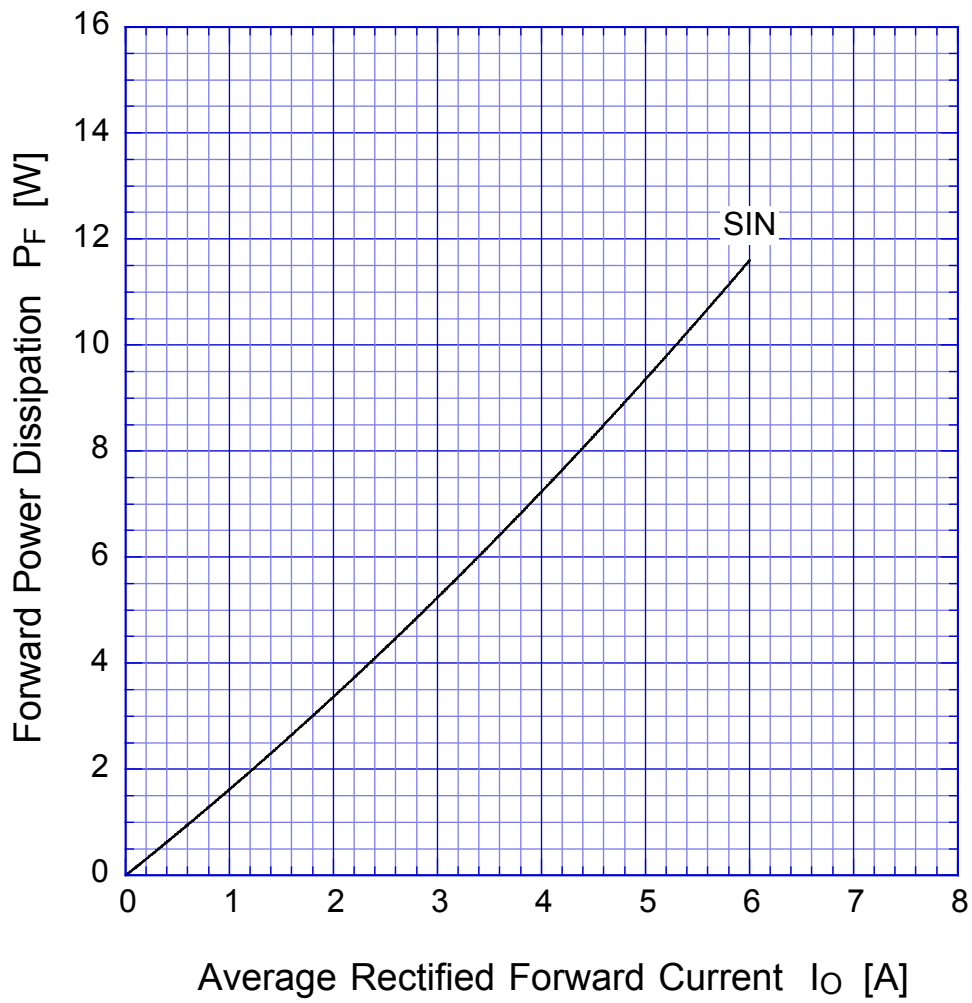
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Forward Voltage



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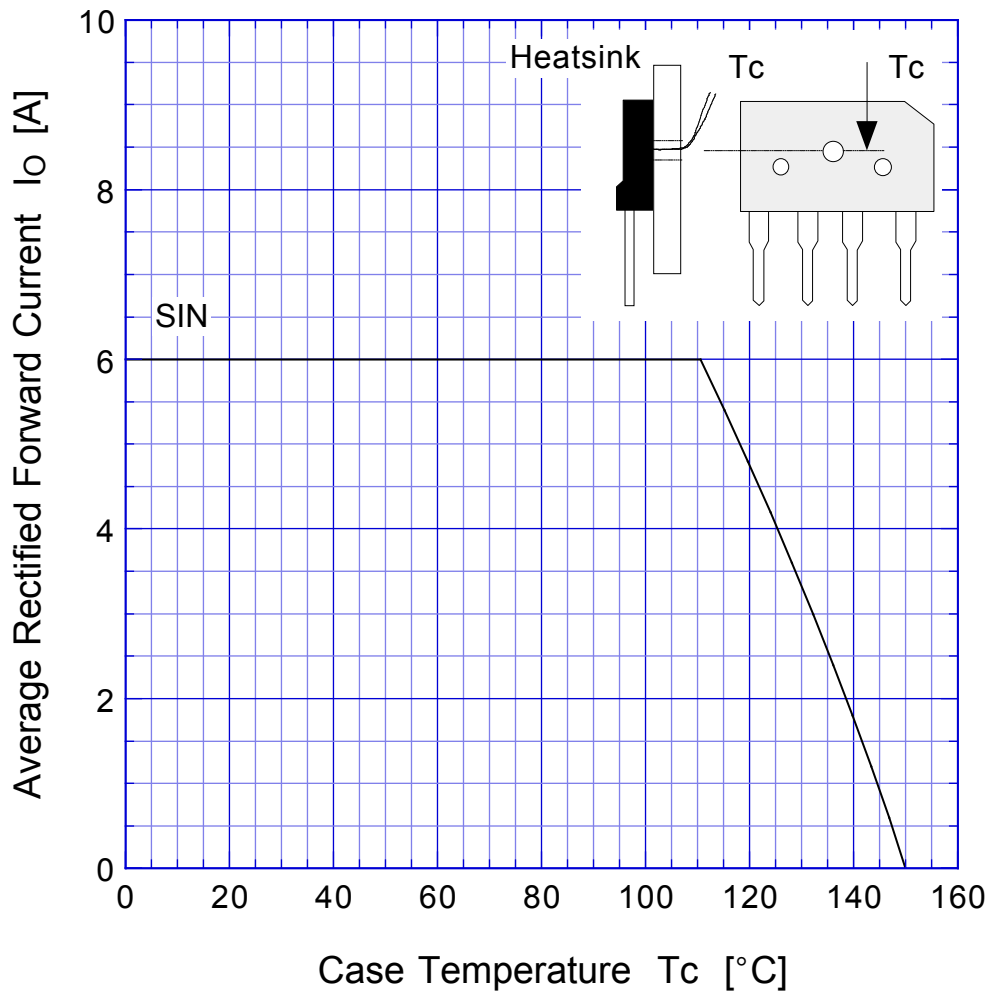
Forward Power Dissipation



$T_j = 150^\circ\text{C}$
Sine wave

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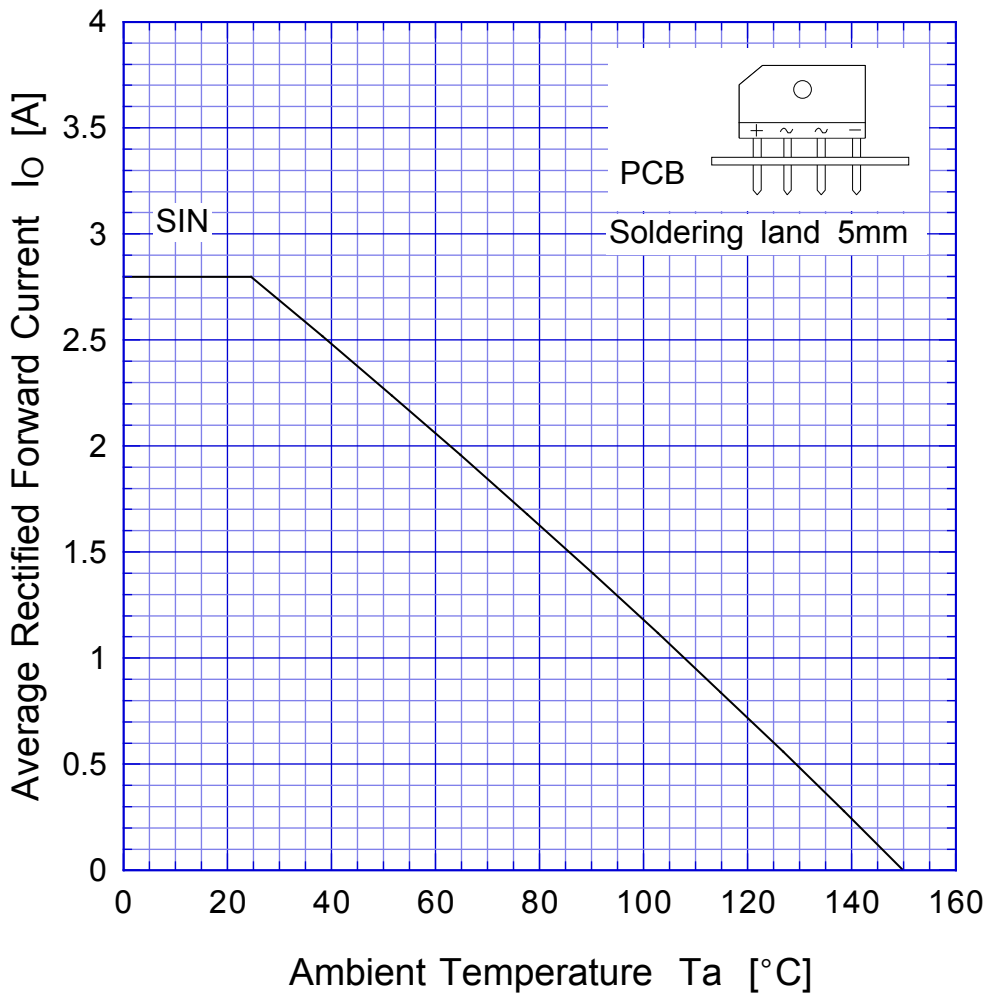
Derating Curve



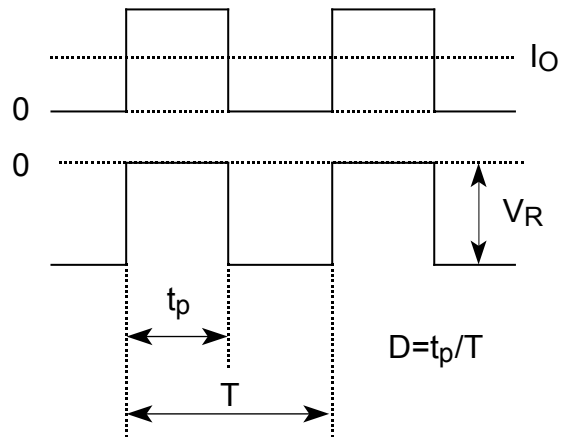
Sine wave
R-load
with heatsink

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Derating Curve



$V_R = 600V$



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Peak Surge Forward Capability

